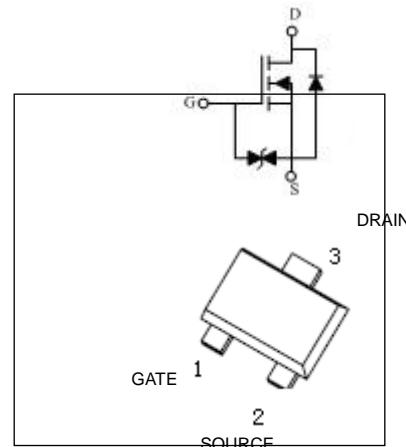




迈拓电子
MAITUO ELECTRONIC

MT3134KM N-Channel MOSFET

| V _{(BR)DSS} | R _{DS(on)MAX} | I _D |
|----------------------|------------------------|----------------|
| 20 V | 380mΩ@ 4.5V | 0.75A |
| | 450mΩ@ 2.5V | |
| | 800mΩ@1.8V | |



FEATURES

- Lead Free Product is Acquired
- Surface Mount Package
- N-Channel Switch with Low R_{DS(on)}
- Operated at Low Logic Level Gate Drive

APPLICATION

SOT-723

- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

MARKING : KF

Maximum ratings (T_a=25°C unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--|-----------------------------------|----------|------|
| Drain-Source Voltage | V _{DS} | 20 | V |
| Typical Gate-Source Voltage | V _{GS} | ±12 | V |
| Continuous Drain Current (note 1) | I _D | 0.75 | A |
| Pulsed Drain Current (t _p =10 μ s) | I _{DM} | 1.8 | A |
| Power Dissipation (note 1) | P _D | 150 | mW |
| Thermal Resistance from Junction to Ambient (note 1) | R _{θJA} | 833 | °C/W |
| Operation Junction and Storage Temperature Range | T _J , T _{STG} | -55~+150 | °C |
| Lead Temperature for Soldering Purposes(1/8" from case for 10 s) | T _L | 260 | °C |



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MOSFET ELECTRICAL CHARACTERISTICS

T_a=25 °C unless otherwise specified

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|---|----------------------|--|------|------|-----|------|
| STATIC CHARACTERISTICS | | | | | | |
| Drain-source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D =250μA | 20 | | | V |
| Zero gate voltage drain current | I _{DSS} | V _{DS} =20V, V _{GS} = 0V | | | 1 | μA |
| Gate-body leakage current | I _{GSS} | V _{GS} =±10V, V _{DS} = 0V | | | ±20 | μA |
| Gate threshold voltage (note 2) | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA | 0.35 | 0.54 | 1.1 | V |
| Drain-source on-resistance (note 2) | R _{DS(on)} | V _{GS} =4.5V, I _D =0.65A | | 270 | 380 | mΩ |
| | | V _{GS} =2.5V, I _D =0.55A | | 320 | 450 | mΩ |
| | | V _{GS} =1.8V, I _D =0.45A | | 390 | 800 | mΩ |
| Forward transconductance (note 2) | g _{FS} | V _{DS} =10V, I _D =0.8A | | 1.6 | | S |
| Diode forward voltage | V _{SD} | I _S =0.15A, V _{GS} = 0V | | | 1.2 | V |
| DYNAMIC CHARACTERISTICS (note 4) | | | | | | |
| Input capacitance | C _{iss} | V _{DS} =16V, V _{GS} =0V, f =1MHz | | 79 | 120 | pF |
| Output capacitance | C _{oss} | | | 13 | 20 | pF |
| Reverse transfer capacitance | C _{rss} | | | 9 | 15 | pF |
| SWITCHING CHARACTERISTICS (note 4) | | | | | | |
| Turn-on delay time (note 3) | t _{d(on)} | V _{GS} =4.5V, V _{DS} =10V, I _D =500mA, R _{GEN} =10Ω | | 6.7 | | ns |
| Turn-on rise time (note 3) | t _r | | | 4.8 | | ns |
| Turn-off delay time (note3) | t _{d(off)} | | | 17.3 | | ns |
| Turn-off fall time (note 3) | t _f | | | 7.4 | | ns |
| Total Gate Charge Q [A] | Q _g | V _{DS} =10V, V _{GS} =4.5V, I _D =500A | | 11.4 | | μC |
| Gate-Source Charge Q [A] | Q _{gs} | | | 1.1 | | μC |
| Gate-Drain Charge Q [A] | Q _{gd} | | | 4.6 | | μC |

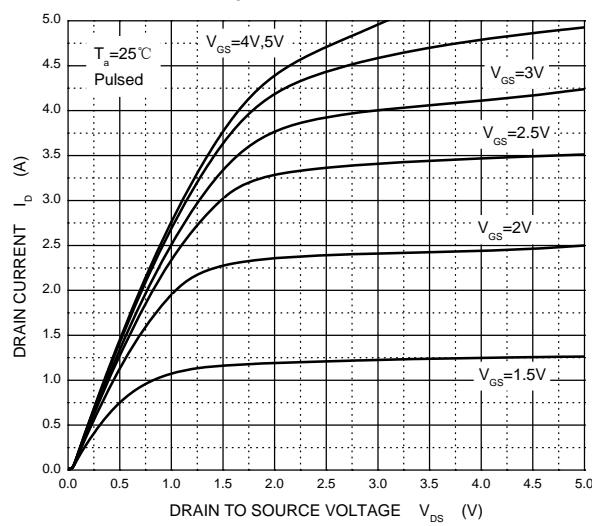
Notes :

1. Surface mounted on FR4 board using the minimum recommended pad size.
2. Pulse Test : Pulse Width=300μs, Duty Cycle=2%.
3. Switching characteristics are independent of operating junction temperatures.
4. Guaranteed by design, not subject to producting.

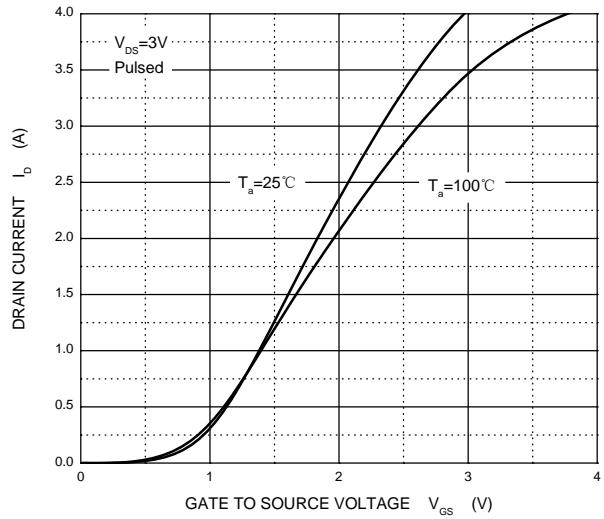


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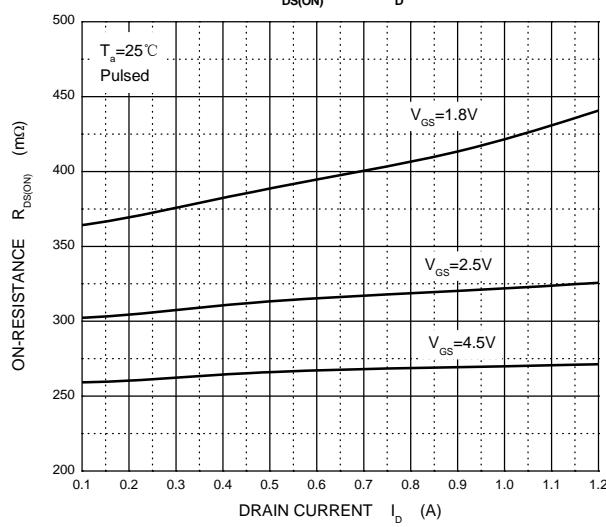
Output Characteristics



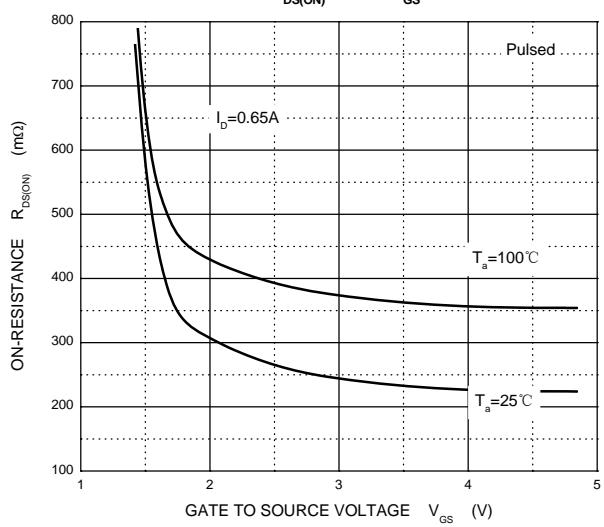
Transfer Characteristics



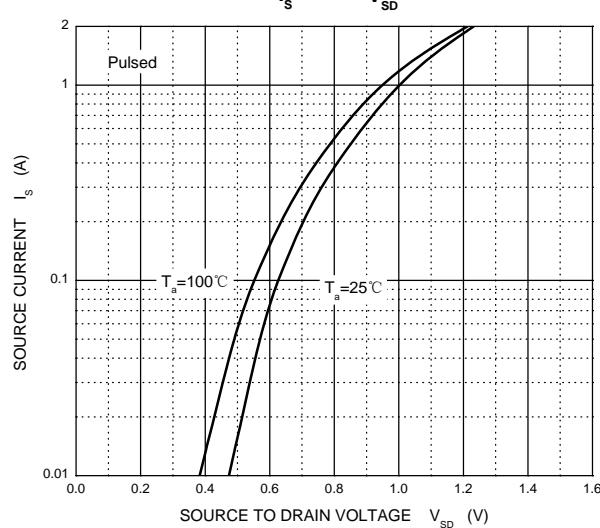
$R_{DS(ON)}$ —— I_D



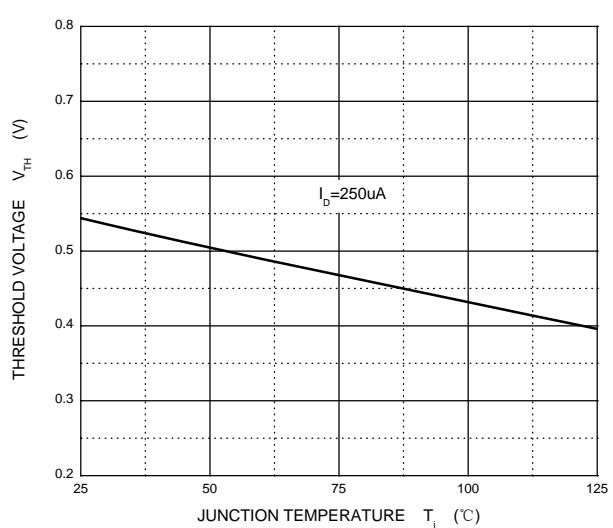
$R_{DS(ON)}$ —— V_{GS}



I_s —— V_{SD}



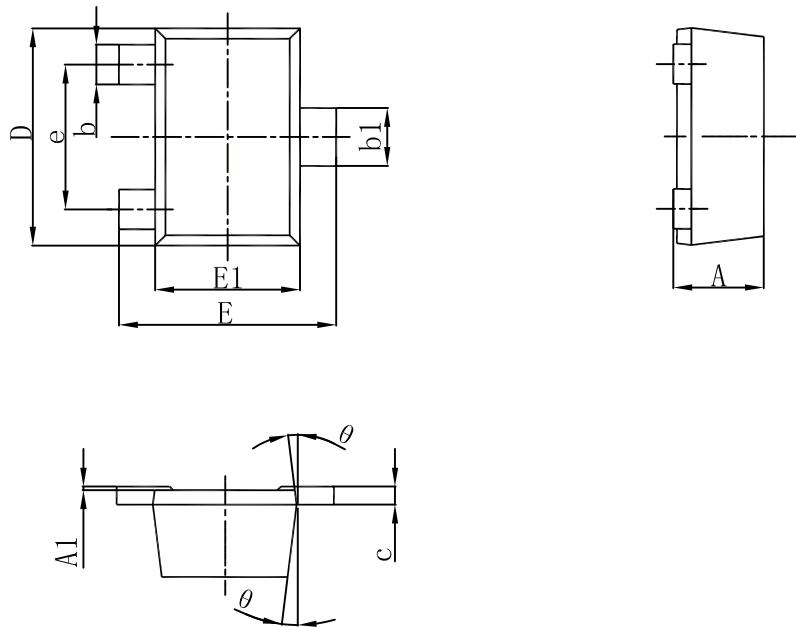
Threshold Voltage





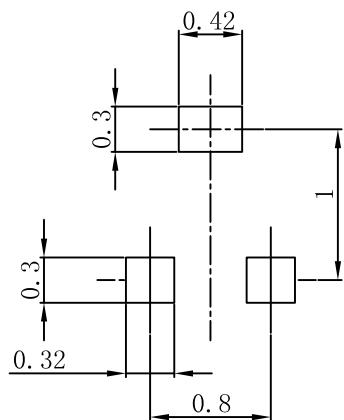
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SOT-723 Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 0.450 | 0.550 | 0.018 | 0.022 |
| A1 | 0.000 | 0.050 | 0.000 | 0.002 |
| b | 0.170 | 0.270 | 0.007 | 0.011 |
| b1 | 0.270 | 0.370 | 0.011 | 0.015 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 1.150 | 1.250 | 0.045 | 0.049 |
| E | 1.150 | 1.250 | 0.045 | 0.049 |
| E1 | 0.750 | 0.850 | 0.030 | 0.033 |
| e | 0.800TYP. | | 0.031TYP. | |
| θ | 7° REF. | | 7° REF. | |

SOT-723 Suggested Pad Layout



Note:
1. Controlling dimension:in millimeters.
2.General tolerance: ± 0.05 mm.
3.The pad layout is for reference purposes only.